Stress-induced magnetic and structural anisotropy of nanocrystalline Fe-based alloys

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(Received 26 March 2010; accepted 30 September 2010; published online 15 November 2010)

The structural anisotropy of Fe–Si–B–Nb–Cu nanocrystalline alloys annealed under tensile stress was studied by x-ray diffraction techniques with transmission geometry. A clear difference was observed in the peak positions of the Fe–Si crystals under two different conditions: with the diffraction vector parallel or perpendicular to the applied stress. The strains calculated from the anisotropy of the peak positions show a linear response to the applied stress, independent of Si content, indicating that the observed structural anisotropy is due to a quenching of the elastic strain, not in the directional ordering of the Fe–Si pair. The induced magnetic anisotropy energy is well explained by the residual strains and their magnetostriction.

I. INTRODUCTION

Fe-based nanocrystalline alloys prepared from amorphous precursors were introduced in 1988.1 Since then, they have been widely used as excellent soft magnetic materials.2 In these alloys, Fe crystals approximately 10 nm in size are formed by the annealing of amorphous ribbons. The origin of the extremely low coercivity is explained by the “random anisotropy model” in which the magneto crystalline anisotropy is averaged out due to the small grain size relative to the exchange coupling length.3 Some applications, such as a choke coil or transformer,4 require a large magnetic anisotropy transverse to the magnetic path. For such applications, annealing in a magnetic field5,6 and/or under tensile stress7,8 is often applied. Annealing under stress is especially attractive due to the wide range of magnetic anisotropy which can be introduced by varying the amount of applied stress.9,10 The result is that the magnetic permeability can be tailored to a required value which is convenient for a particular industrial application. Therefore, since the 1970s, when amorphous and nanocrystalline ferromagnetic ribbons were produced by the rapid quench method, there have been a series of studies concerned with stress-induced anisotropy. In contrast, the structural origin of the magnetic anisotropy was unclear for about three decades until the anisotropy in the lattice plane was actually observed by transmission x-ray diffraction techniques.11,12 This lattice plane anisotropy shows a linear response to the applied stress, which indicates that the anisotropy originates from residual elastic strain. However, the observed lattice spacing anisotropy may include some contribution from the directional ordering of Fe–Si atomic pair effects introduced by stress annealing. In the present work we have investigated an alloy series with varying silicon content in order to study the magnitude of pair ordering effects via t-XRD. Differences in the anisotropy of different atomic planes are also discussed in order to understand the relationship between the bulk behavior and the observed changes in lattice planes of the ribbons.

II. EXPERIMENTAL

Amorphous ribbons of Fe73.5SiXB22.5-XNb3Cu1 (X = 9, 15.5) and Fe77.5B15.5Nb3Cu1 5 mm wide were prepared by the rapid quench method.1,5,10 The Fe73.5SiXB22.5-XNb3Cu1 ribbons were heated to 550 °C and kept at that temperature for 20 min while applying different tensile stresses, and the annealing temperature was 450 °C for Fe77.5B15.5Nb3Cu1. The details of the annealing settings have been described elsewhere.10 The t-XRD was measured using a conventional XRD system with Mo-Kα radiation, an incident monochromator, and a solid state detector to cut the fluorescence effect.12 The incident x-ray beam was aligned θ from the normal vector of the ribbons, and the diffracted beam was also aligned θ from the normal vector of the opposite side of the ribbons. Consequently, the diffraction vector q was fixed in the ribbon plane as schematically shown in Fig. 1. Two measurements were conducted for each sample: one for the measurement in which the diffraction vector is parallel to the ribbon direction (the same direction as the applied tensile stress), and the other for the diffraction vector parallel to the ribbon width direction, i.e., perpendicular to the stress direction. All of the t-XRD measurements were performed at room temperature after releasing the stress. The uniaxial magnetic anisotropy energy, Kuv, was calculated from the anisotropy field, Hk, and the saturation magnetization, Bs, was measured at room temperature after releasing the stress (not reported in this paper).

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III. RESULTS AND DISCUSSIONS

Figure 2 shows the t-XRD profiles for the Fe₇₇.₅B₁₅.₅Nb₃Cu₁ and Fe₇₃.₅Si₉B₁₃.₅Nb₃Cu₁ alloys annealed under different tensile stresses. A clear change of the peak position is observed even in the alloy without Si, which indicates that the observed structural anisotropy is not related to Fe–Si pair ordering. The measured values of the lattice spacing of the alloys annealed under different stresses are plotted together with previous results for Fe₇₃.₅Si₁₅.₅B₇Nb₃Cu₁ in Fig. 3. All of the data show a linear relationship, and their gradients are about the same for all of the alloys, almost independent of Si concentration. Therefore, it is concluded that the structural anisotropies in the lattice spacing of the alloys with and without Si are predominantly due to elastic residual strain, and the contribution of Fe–Si pair ordering is negligible.

When the elastic strain exists in ferromagnetic materials, uniaxial magnetic anisotropy is induced due to the magnetoelastic effect. In the present experimental situation, we basically deal with a simple, uniaxial stress strain experiment for an isotropic material. Furthermore, the structural correlation lengths for both the amorphous matrix and the randomly oriented crystallites are smaller than the ferromagnetic exchange length. Thus, exchange interaction effectively reduces the magnetostriction tensor to an isotropic fourth rank tensor characterized by a single magnetostriction coefficient, the saturation magnetostriction constant $\lambda_s$. Accordingly, the theoretical description of the average magnetoelastic interaction can be simplified drastically. As a result the induced magnetic anisotropy energy constant, $K_u$, can be related to the strain as follows:

$$K_u = -\frac{3}{2}E e_{\parallel} \lambda_s,$$

where $E$, $e_{\parallel}$, and $\lambda_s$ are the elastic modulus, elastic strain parallel to the stress, and saturation magnetostriction, respectively. By convention, $K_u > 0$ hereby refers to a magnetic easy perpendicular to the strain axis. As described above, the observed anisotropy corresponds directly to residual elastic strain. Therefore, strain parallel to the applied stress for the sample annealed under $x \text{ MPa}$, $e_{\parallel}^{x \text{ MPa}}$, can be defined by the following equation:

$$e_{\parallel}^{x \text{ MPa}} = \frac{d_{\parallel}^{x \text{ MPa}} - d_{\parallel}^{0 \text{ MPa}}}{d_{\parallel}^{0 \text{ MPa}}},$$

where, $d_{\parallel}^{x \text{ MPa}}$ and $d_{\parallel}^{0 \text{ MPa}}$ is the lattice spacing of the samples annealed under $x \text{ MPa}$ and 0 MPa obtained from t-XRD peak positions, respectively. Due to the annealing facility used, the value of $d_{\parallel}^{10 \text{ MPa}}$ annealed under 10 MPa instead of 0 MPa is used here-for the minimum stress value, which yields the isotropic peak positions shown in Fig. 2.

The relationship between $K_u$ and $e_{\parallel}$ is again linear, as shown in Fig. 4. This means that Eq. (1) is applicable, and therefore, the induced magnetic anisotropy is magnetoelastic in origin. Taking the small effect of Si content on the elastic
modulus into account, the difference of the gradient is mainly attributable to the $\lambda_s$, which is the largest for the Fe$_{73.5}$Si$_{15.5}$B$_7$Nb$_3$Cu$_1$ alloy.

To evaluate the value of $\lambda_s$, an evaluation of the Young’s modulus is necessary. The simplest model of stress-strain distribution in the polycrystalline system can be either uniform strain or uniform stress distributions. In the former model, each grain shows same elongation, while the each grain elongate under the uniform stress. Usually most of the polycrystalline system is in between two models. To clarify our case, we measure different lattice strains parallel to tensile stress. Figure 5 shows the t-XRD results for four different index planes of the Fe$_{3}$Si phase in an Fe$_{73.5}$Si$_{15.5}$B$_7$Nb$_3$Cu$_1$ alloy annealed under 10, 213, and 461 MPa. The observed anisotropy of the planes shows a large difference depending on the index of the planes, even in samples annealed under the same stress. The diffraction peak for (440), (620), and (642) shows clear anisotropy, while the peak for (444) shows little anisotropy under all applied stresses. Using Eq. (2), the strain, $\epsilon_t$, for each index plane is evaluated and plotted in Fig. 6. The results show the different strains depending on the index, indicating that the studied alloy is far from uniform strain condition. Table I shows the elastic modulus for each direction from the gradient assuming an elastic response to the applied stress. Obtained values are about 100, 400, and 500 GPa in the [310], [110], and [321] directions, respectively. The small change of the (444) planes suggests that the elastic modulus for the [111] direction is even larger than in the [321] direction. The difference in the elastic modulus corresponds to the difference of elastic modulus for single crystals. For the cubic system, the specific modulus for single crystalline $hkl$ plane, $E_{hkl}$, can be described as

$$1/E_{hkl} = S_{11} - 2(S_{11} - S_{12} - 1/2S_{44})A_{hkl},$$

where $S_{ij}$ in the single crystal compliance tensor in collapsed matrix notation and $A_{hkl}$ is

$$A_{hkl} = (h^2k^2 + h^2l^2 + k^2l^2)/(h^2 + k^2 + l^2)^2.$$  

Using Eqs. (3) and (4), and the published dependence of $S_{11}$, $S_{12}$, $S_{44}$ on Si concentration, $^{14}$ $E_{hkl}$ for Fe-20at. %Si single crystal can be calculated and listed in Table I. As shown in Table I, the observed modulus relates to the elastic nature in each direction, qualitatively, i.e., [310] direction is softer direction, [110] and [321] are similar values within the error, and [111] is the hardest directions among them. These facts suggest that the residual strain is formed under a uniform stress condition in which all grains are under the same stress. Therefore, depending on the crystalline direction of each nanosingle crystal, the elastic response is different parallel to the tensile stress. This is reasonable for the case where the residual amorphous phase with an isotropic nature already in the plastic region at high temperature is a medium for uniform stress distribution. There are still some differences between observed and calculated elastic modulus. This is partially attributed to the fact that the amorphous matrix exceeds the elastic limit due to softening, which is characteristic of

![FIG. 5. (Color online) XRD profiles of four different index planes [(440), (620) (444) and (642)] of Fe$_{3}$Si phase in an Fe$_{73.5}$Si$_{15.5}$B$_7$Nb$_3$Cu$_1$ alloy annealed under 10, 213, and 461 MPa, from bottom to top. Circles and curves indicate t-XRD profiles with diffraction vector parallel and perpendicular to the applied stress, respectively.]

![FIG. 6. (Color online) Strains, $\epsilon_t$, for different index planes measured parallel to applied stress plotted as a function of applied stress during annealing. Circles: (620), squares: (440), triangles: (642), diamonds: (444) planes.]

**TABLE I.** Observed and calculated elastic modulus, $E_{hkl}^{obs}$, $E_{hkl}^{calc}$ and $A_{hkl}$ for Fe-20at. %Si bcc crystals.

<table>
<thead>
<tr>
<th>Index of planes</th>
<th>$E_{hkl}^{obs}$ (GPa)</th>
<th>$E_{hkl}^{calc}$ (GPa)</th>
<th>$A_{hkl}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>100</td>
<td>...</td>
<td>103</td>
<td>0</td>
</tr>
<tr>
<td>111</td>
<td>...</td>
<td>313</td>
<td>0.333</td>
</tr>
<tr>
<td>220</td>
<td>403+/-50</td>
<td>208</td>
<td>0.25</td>
</tr>
<tr>
<td>310</td>
<td>99+/-20</td>
<td>126</td>
<td>0.09</td>
</tr>
<tr>
<td>321</td>
<td>535+/-60</td>
<td>208</td>
<td>0.25</td>
</tr>
</tbody>
</table>
non-crystalline materials. Therefore, the effective cross section that behaves elastically is smaller than that of ribbons. In addition, observed elastic moduli, $E_{\text{bkl}}^{\text{obs}}$ of Fe–Si crystals correspond to those of the annealing temperature where the stress is loaded. They can be different from $E_{\text{bkl}}^{\text{cal}}$ which are calculated from the $S_{ij}$ values obtained at room temperature. In contrast, because $K_u$ is measured at room temperature, the elastic modulus at room temperature should be used for the analysis of the magnetoelastic effect. Therefore, calculated $E_{310}^{\text{cal}}$ is used as the best approximation for discussing the relationship between $K_u$ and $e_i$ determined from (620)/(310) planes in the following part.

The strains obtained from the XRD profiles are purely from bcc crystals. In contrast, the anisotropic energy, $K_u$, obtained from magnetic measurements corresponds to one from both bcc and amorphous phases. Thus, the effect of volume fraction on $K_u$ must be taken into account following the method proposed by Herzer. In this model, the saturation magnetostriction of the ribbon, $\lambda_s^{\text{ribbon}}$, is given by the simple sum of the magnetostriction of the Fe–Si nanocrystals, $\lambda_s^{\text{Fe–Si}}$, and that of the remaining amorphous material, $\lambda_s^{\text{AM}}$, weighted by their volume fractions:

$$
\lambda_s^{\text{ribbon}} = v_{\text{Fe–Si}} \lambda_s^{\text{Fe–Si}} + (1 - v_{\text{Fe–Si}}) \lambda_s^{\text{AM}}.
$$

Here, $v_{\text{Fe–Si}}$ is the volume fraction of the Fe–Si nanocrystals, which can be evaluated from the valance of the chemical composition under the assumption that perfect partitioning of Si, B, Nb, and Cu to the constituent phases occurs as follows:

$$
\text{Fe–Si} + \text{B} + \text{Nb} + \text{Cu} \rightarrow v_{\text{Fe–Si}} \gamma_{\text{Fe–Si}} + (0.99 - v_{\text{Fe–Si}}) (\text{Fe}_{1-x} \text{Nb}_x) \text{Si}_y + 0.01 \text{Cu}.
$$

Here, $y$ is the Si content in the Fe–Si nanocrystals, and $a$ is the Nb content in the remaining B-rich amorphous phase. The value of 2.2 is adopted from Ref. 15 for $n$. Consequently, the volume fraction and the Si content in the Fe–Si phase are evaluated and listed in Table II. In order to understand what happens on average along the applied stress axis, the contribution of the Fe–Si phase to the magnetic anisotropy, $K_u^{\text{Fe–Si}}$, can be correlated with the residual stress of Fe–Si phase, $\sigma_{ij}^{\text{Fe–Si}}$, parallel to the applied stress direction. For evaluating average $\sigma_{ij}^{\text{Fe–Si}}$, $e_i$ determined from (620)/(310) peak and the elastic modulus, $E_{310}$ is used under the assumption of uniform stress condition, i.e., $\sigma_{ij}^{\text{Fe–Si}} = e_i E_{310}$. Therefore, $K_u^{\text{Fe–Si}}$ can now be rewritten using Eqs. (1) and (3) as follows (cf [8]):

$$
K_u^{\text{Fe–Si}} = -\frac{1}{2} v_{\gamma_{\text{Fe–Si}}} E_{310} e_i \lambda_s^{\text{Fe–Si}}.
$$

Consequently, the saturation magnetostriction, $\lambda_s^{\text{Fe–Si}}$, can be calculated from the gradient of the lines shown in Fig. 4 using $v_{\gamma_{\text{Fe–Si}}}$ and $E_{310}$ calculated from Eqs. (3) and (4) with the elastic strains of bcc Fe–Si for corresponding Si content. The $\lambda_s^{\text{Fe–Si}}$ values obtained are $-0.6$ ppm, $-3.3$ ppm, and $-7.7$ ppm, respectively, and listed in Table II together with each $E_{310}$. Those values are plotted together with the results for the Fe–Si phase in Fe–Si–B–Nb–Cu alloys and for conventional Fe–Si alloys in Fig. 7. Although simple models are used for evaluating the Si content and the volume fraction of Fe–Si crystals, the results show excellent agreement with the previous data, again indicating that the induced magnetic anisotropy is a magnetoelastic effect.

### IV. SUMMARY

The anisotropy of the lattice spacing in Fe–Si nanocrystals of Fe–Si–B–Nb–Cu alloys annealed under different stresses was studied, resulting in the following:

1. All alloys show structural anisotropy when annealed under a certain stress.
2. Independent of Si content, a linear response between applied stress and strain was determined from the structural anisotropy.
3. The elastic constant determined from the gradient of the strain-applied stress plot shows a strong dependence on the lattice plane. The origin of the difference can be understood from the anisotropic elastic nature of each single crystal. It also indicates that the nanocrystals in the alloys are under uniform stress conditions during annealing.
4. The dependence of the magnetic anisotropy on composition is explained by the corresponding variation of the local magnetostriction, $\lambda_s^{\text{Fe–Si}}$ of the crystallites. The $\lambda_s^{\text{Fe–Si}}$ determined from structural anisotropy agrees well with bulk values in conventional Fe–Si and nanocrystalline alloys.

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**TABLE II. Volume fraction $v_{\text{Fe–Si}}$ and Si content in Fe–Si crystals evaluated from mass balance of Eq. (5) Corresponding Elastic modulus for [310] direction calculated from Eqs. (3) and (4) and obtained $\lambda_s$ are also listed.**

<table>
<thead>
<tr>
<th>Alloy comp.</th>
<th>$v_{\text{Fe–Si}}$ (at. %)</th>
<th>$E_{310}$ (Gpa)</th>
<th>$\lambda_s$ (ppm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Fe$<em>{72.5}$Si$</em>{15.5}$B$_7$Nb$<em>3$Cu$</em>{0.77}$</td>
<td>0.49</td>
<td>0</td>
<td>153</td>
</tr>
<tr>
<td>Fe$<em>{73.5}$Si$</em>{9}$B$_{13.5}$Nb$<em>3$Cu$</em>{0.56}$</td>
<td>0.56</td>
<td>16</td>
<td>126</td>
</tr>
<tr>
<td>Fe$<em>{73.5}$Si$</em>{15}$B$_7$Nb$<em>3$Cu$</em>{0.77}$</td>
<td>0.77</td>
<td>20</td>
<td>126</td>
</tr>
</tbody>
</table>

**FIG. 7. (Color online) Dependence of $\lambda_s$ on Si content in Fe–Si crystals. Solid circles: $\lambda_s$ determined in this study. Other markers: $\lambda_s$ adopted from Ref. 8 in different Si and B content of Fe–Si–B–Nb–Cu nanocrystalline alloys (cross: 18.5; triangle: 20.5; square: 22.5; diamond: 23.5 at % of the sum of Si and B content in the alloys). Dotted lines: polycrystalline Fe–Si alloys (Ref. 16).**

$$
K_u^{\text{Fe–Si}} = -\frac{1}{2} v_{\gamma_{\text{Fe–Si}}} E_{310} e_i \lambda_s^{\text{Fe–Si}}.
$$

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ACKNOWLEDGMENT

This work was partially supported by KAKENHI JSPS-18360340.